

Quantum critical behavior of magnetic quantum paraelectrics

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(Dated: October 22, 2009)

We discuss the interplay between anti-ferromagnetic order and polarization fluctuations in a *magnetic quantum paraelectric*. Using an action where anti-ferromagnetic order parameter couples to the polarization fluctuations and as well as magnetic field, we derive a set of self consistent equations to study both the temperature and the magnetic field dependence of the static dielectric susceptibility. The temperature dependence of dielectric susceptibility near both the anti-ferromagnetic quantum critical point and ferroelectric quantum critical point are described with scaling arguments. Discussions on achieving various quantum critical points in experiments are also made.

PACS numbers: 74.40.Kb, 63.70.+h

INTRODUCTION

EuTiO₃ can be considered as a good addition in the list of perovskite materials exhibiting macroscopic quantum phenomena in ferroelectrics and multiferroics. As far as the structure and the gross features of static dielectric behavior are concerned, this material is similar to the prototype quantum paraelectrics with perovskite structure, like SrTiO₃, KTaO₃, etc. All these materials are incipient ferroelectric, i.e. they do not undergo any ferroelectric transition at finite temperature, rather their static dielectric susceptibilities reach a very high, temperature independent value ($\epsilon_0 \sim \mathcal{O}(10^4)$ for SrTiO₃) at low temperature. Ferroelectric transitions in materials which are similar in structure, for example in BaTiO₃, is of displacive type and is well described by softening of a zone center transverse optical mode at some finite temperature. This scenario, that is, the absence of transition and the saturation at high dielectric susceptibility, has been attributed to the smallness of the zero temperature gap in the corresponding optical branch. In recent years there is a revival of theoretical discussions on these materials in context of quantum phase transitions. Recently these materials have been studied in a perspective of quantum phase transition and fluctuations around it [1, 2, 3, 4, 5]. In the study of quantum criticality in ferroelectrics, EuTiO₃ certainly adds a new dimension. This material contains magnetic Eu with spin 7/2, which undergoes anti-ferromagnetic order at $T_N \sim 5.3K$ [6]. Magnetic order in this material couples to polarization fluctuations and produces a sharp decrease in the static dielectric susceptibility below the Neel temperature. Electric polarization in this material is due to the variations of Ti-O bond-lengths from their equilibrium values. However the collective behavior of such interacting stretched bonds does not lead to a ferroelectric state even at zero temperature.

At the critical value of the external magnetic field ~ 1 Tesla, which suppresses the effects of the Neel order completely, the static dielectric constant of this material attains a quantum paraelectric behavior, with $\epsilon_0 \sim \mathcal{O}(10^2)$ at zero temperature [7]. The dielectric susceptibility starts getting saturated at a crossover temperature (as defined in ref. [1]) $\sim 30K$. In the present work, we consider the ferroelectric subsystem as displacive type, i.e. corresponding order parameter ($\vec{P}$) fluctuations are represented by the fluctuations in two transverse optic branches. Ferroelectric transition in this case is due to the softening of the optic phonons at the zone center. The effects of dipolar interaction is considered as the stiffening of longitudinal branch, and thus longitudinal fluctuations are not taken into account. Magnetic sector, i.e. the collection of interacting Eu spins in a cubic perovskite environment, is represented by Heisenberg anti-ferromagnetic order parameter ($\vec{m}$) which is a vector spin with three components with short range interactions. The effects of the crystal anisotropy are not attempted here, thus all the quartic terms are taken as isotropic. We consider a coupling of the form $\frac{w}{2} |\vec{P}|^2 |\vec{m}|^2$ with coupling constant $w > 0$, between them and focus on the dependencies of the static dielectric susceptibility on temperature and external magnetic field below T_N . In the previous theoretical works [8, 9], the effects of magnetoelectric coupling on the thermodynamic behavior of this material are described at mean field level. But no attention is paid on the possible quantum critical behavior of this system. We will try to explore the behavior of the static dielectric constant in the theoretically interesting anti-ferromagnetic quantum critical point and ferroelectric quantum critical point regime, and discuss the possibility of realizing such a limit in experiments, in the following sections.

THEORY

In the vicinity of quantum critical points, a Landau-Ginzburg-Wilson action for a magnetic quantum paraelectric system, in terms of the sub-lattice magnetization $\vec{m}$ and the electric polarization $\vec{P}$ (soft mode coordinates) can be written in the following form,

$$\begin{aligned}
S = & \int d^d x \int_0^\beta d\tau [(\partial_\tau \vec{P})^2 + (\partial_\tau \vec{m} - i\vec{h} \times \vec{m})^2 \\
& + \frac{c_e}{2}(\nabla \cdot \vec{P})^2 + \frac{c_m}{2}(\nabla \cdot \vec{m})^2 + \frac{r_e}{2}(\vec{P} \cdot \vec{P}) \\
& + \frac{r_m}{2}(\vec{m} \cdot \vec{m}) + \frac{u}{2}(\vec{P}^2)^2 + \frac{v}{2}(\vec{m}^2)^2 \\
& + \frac{w}{2}|\vec{P}|^2|\vec{m}|^2] \quad (1)
\end{aligned}$$

Here τ is the imaginary time, β is the inverse temperature, and $\vec{h}$ is the applied external uniform mag-

netic field. The parameters r_e and r_m can be tuned to zero to have ferroelectric and anti-ferromagnetic instabilities respectively. The coupling constants of the quartic terms are positive, i. e. $u, v > 0$, to ensure the stability of the system. Since in a quantum picture statics and dynamics are coupled, an applied magnetic field induced precession of the magnetic vectors also play an important role in the study of phase transitions in quantum magnets. Now we start our discussions with the following *mean field approximations*.

$$\begin{aligned}
\vec{m}(\vec{q}, \omega) &= m_0 \hat{z} \delta(\vec{q}) \delta(\omega) + \vec{m}'(\vec{q}, \omega), \\
\langle \vec{m}' \rangle &= 0, \quad \langle \vec{P} \rangle = 0 \quad (2)
\end{aligned}$$

Here $\vec{m}(\vec{q}, \omega)$ is the Fourier transform of $\vec{m}(\vec{x}, \tau)$. The above approximations, along with the RPA decoupling of the quartic terms, lead to the following mean field action,

$$\begin{aligned}
S_{MF} = & \frac{r_m}{2} m_0^2 + \frac{v}{2} m_0^4 + \int d^d q \frac{1}{\beta} \sum_n [(\frac{r_e}{2} + \omega_n^2 + \frac{c_e q^2}{2} + \frac{u}{2} \lambda_e)(\vec{P} \cdot \vec{P}) + (\omega_n \vec{m}' - i\vec{h} \times \vec{m}')^2 \\
& + (\frac{c_m q^2}{2} + \frac{r_m}{2} + \frac{v}{2}(2m_0^2 + \lambda_m))(\vec{m}' \cdot \vec{m}') + \frac{w}{2}(m_0^2 + \vec{m}' \cdot \vec{m}') \vec{P} \cdot \vec{P}] \quad (3)
\end{aligned}$$

In the above expression, $\vec{A} \cdot \vec{A} = \vec{A}(\vec{q}, \omega_n) \cdot \vec{A}(-\vec{q}, \omega_n)$, $\lambda_{(e,m)} = \int d^d q \frac{1}{\beta} \sum_n \chi_{(e,m)}(\vec{q}, \omega_n)$ and

$$\chi_e(\vec{q}, \omega_n) = \langle \vec{P}(\vec{q}, \omega_n) \cdot \vec{P}(-\vec{q}, \omega_n) \rangle, \quad \chi_m(\vec{q}, \omega_n) = \langle \vec{m}'(\vec{q}, \omega_n) \cdot \vec{m}'(-\vec{q}, \omega_n) \rangle \quad (4)$$

Zero magnetic field ($h = 0$): In a zero external magnetic field, the self consistent equations for polarization and magnetic fluctuations are,

$$\begin{aligned}
& \chi_e(\vec{q}, \omega_n) \\
& = \langle \vec{P}(\vec{q}, \omega_n) \cdot \vec{P}(-\vec{q}, \omega_n) \rangle \\
& = \frac{1}{\frac{r_e}{2} + \frac{c_e q^2}{2} + \omega_n^2 + \frac{w}{2}(m_0^2 + \lambda_m) + \frac{u}{2} \lambda_e}, \quad (5)
\end{aligned}$$

and

$$\begin{aligned}
& \chi_m(\vec{q}, \omega_n) \\
& = \langle \vec{m}'(\vec{q}, \omega_n) \cdot \vec{m}'(-\vec{q}, \omega_n) \rangle \\
& = \frac{1}{\frac{r_m}{2} + \frac{c_m q^2}{2} + \omega_n^2 + \frac{w}{2} \lambda_e + \frac{v}{2}(2m_0^2 + \lambda_m)} \quad (6)
\end{aligned}$$

respectively. The above two equations should be supplemented by the following expression for the *magnetic free energy* (within one loop correction) to

determine m_0 in the magnetically ordered phase.

$$\begin{aligned}
f_m = & \frac{r_m}{2} (m_0^2)^2 + \frac{v}{2} |m_0|^4 \\
& - \frac{1}{2} T r \log(\chi_m(\vec{q}, \omega_n)) \quad (7)
\end{aligned}$$

We need to know m_0 , λ_e , and λ_m as a function of the temperature at various values of the system parameters, using equations [5-7]. The extremization of f_m with respect to m_0 gives,

$$r_m m_0 + 2v m_0^3 + v m_0 \int d^d q \frac{1}{\beta} \sum_n \chi_m(\vec{q}, \omega_n) = 0 \quad (8)$$

Non-zero solution of m_0 reads as,

$$m_0^2 = \frac{-r_m - v \lambda_m}{2v} \quad (9)$$

At this point we emphasize that at the critical value of the magnetic field, where the magneto-electric coupling is believed to be very small, the

static dielectric constant for EuTiO_3 reaches a value $\mathcal{O}(10^2)$. Thus according to the classifications of various quantum paraelectrics the ferroelectric subsystem falls into the category of the *gapped quantum paraelectrics*, and is much more away from the ferroelectric quantum critical point than SrTiO_3 . Such a dielectric state is characterized by a *crossover temperature* $T^* \sim \sqrt{r_e}$. Thus for pure EuTiO_3 , we assume the ferroelectric crossover temperature T^* is much higher than T_N , the Neel temperature. Low T_N implies that, the system is in the vicinity of anti-ferromagnetic quantum critical point. In that case λ_e to be temperature independent and consider the temperature dependence of λ_m near as well as away from the magnetic critical point. Within a non-self consistent estimate,

$$\chi_e^{-1}(0,0) \sim \begin{cases} \tilde{r}_e - T^2 & (\text{near AFM - QCP}) \\ \tilde{r}_e - T & (\text{large } T_N) \end{cases} \quad (10)$$

Here $\tilde{r}_e$ is the re-normalized value of r_e . Thus we see that, dielectric measurements can be considered as an indirect thermodynamic probe for magnetic systems in a magnetic quantum paraelectrics. In next section we will consider change in the dielectric behavior in this system in case of field induced transition in the magnetic subsystem.

Non-zero magnetic field ($h \neq 0$): Non-zero h modifies anti-ferromagnetic order, develops a ferromagnetic order along the direction of the field and the resulting magnetic configuration becomes *canted*[10]. Firstly it is apparent from our starting action (eqn.[1]) that in case non zero h along the z-direction, anti-ferromagnetic gap in the transverse plane (with respect to the field) changes to,

$$r_m \sim r_m(0) - h^2 \quad (11)$$

Where $r_m(0) < 0$ is the value of r_m at zero magnetic field. Thus h reduces the gap in the transverse directions. In the regime $r_m < 0$ and $|r_m| > h^2$, m_0 is still non-zero and it increases with increasing h in the following manner,

$$m_0 \sim (h^2 - r_m(0))^{\frac{1}{2}} \sim (h - h_0)^{\frac{1}{2}} \quad (12)$$

Where $h_0 = \sqrt{r_m(0)}$. But the ferromagnetic order along the direction along the field grows more rapidly as follows,

$$m_{fm} = -\frac{\partial F}{\partial h} \sim \frac{h(h^2 - r_m(0))}{v} \quad (13)$$

A schematic phase diagram for field induced transition in the magnetic subsystem is shown in figure [1]. In our case $r_m(0)$ is negative and we consider

the external magnetic field induced modification of the anti-ferromagnetic -ground state to a canted state with partial ferromagnetic order and its effect on the static dielectric susceptibility. An experimentally observed fact is that the increase in anti-ferromagnetic component results in the suppression of dielectric constant while the roll of the uniform component is just opposite to it. If we assume both the components couple to the polarization in the same fashion, we can make an estimate of the critical value of the magnetic field (h_c) which exactly nullifies the effects of magnetic order on the static dielectric constant, in the following way. Using eqn. [12] and [13] we get,

$$\begin{aligned} (h_c^2 - r_m(0)) &= \frac{1}{c} \times h_c^2 (h_c^2 - r_m(0))^2 \\ \Rightarrow h_c &= \frac{r_m(0) \pm \sqrt{r_m^2(0) + 4c}}{2} \end{aligned} \quad (14)$$

Where c is a non-universal constant and so is h_c . Thus at $r_m(0) = 0$ i. e. at anti-ferromagnetic quantum critical point, $h_c \sim \sqrt{c}$. Apart from this, external magnetic field has one more effect on quantum criticality. In case of field induced transition, the

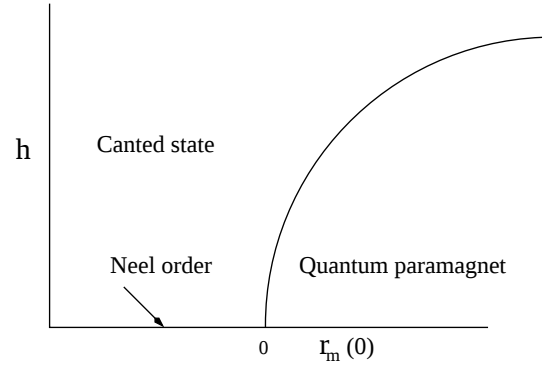


FIG. 1: Figure shows the schematic phase diagram for a field induced transition in insulating Heisenberg anti-ferromagnet at zero temperature. At $h = 0$, $r \leq 0$ indicates a Neel order and $h \neq 0$, $r < 0$ region represents a Canted state with both ferromagnetic and anti-ferromagnetic order[10].

finite temperature behavior near quantum critical point will also be different. If we look back the action[1], we see that the magnetic field adds a new dynamic term $\sim -i\vec{h} \times \vec{m}' \cdot \partial_\tau \vec{m}'$ which is linear in ω_n . Thus the dynamic exponent $z = 2$ in this case. For small h , i. e. when $m_{fm} \ll m_0$, one would expect a $T^{3/2}$ contribution (weighted by $h^{\frac{1}{2}}$), from the magnetic subsystem to the static dielectric susceptibility at low temperature near anti-ferromagnetic quantum critical point. Here we assume that the ap-

plied field is too small to induce metaelectric transition and neglect $\hbar$ dependence of the $T^{3/2}$ contribution for rest of the discussions.

Near ferroelectric quantum critical point: So far, we have considered the dielectric subsystem as a spectator with a temperature independent dielectric susceptibility at low temperature. However, one can make T^* closer or smaller than T_N through doping. A generic possibility is replacing O^{16} by O^{18} in EuTiO_3 , as is done in case of SrTiO_3 [11]. Such a doping can create a reduced crossover temperature $\tilde{T}^*(x) \sim (1-x)^{1/2}T^*$, (where x is the impurity concentration) and move the system towards ferroelectric quantum critical point without affecting the magnetic subsystem. At finite temperature near ferroelectric quantum critical point, dipolar contribution to the inverse static dielectric constant is $\sim T^2$ which will compete with negative contribution ($\sim -T^\nu$, $\nu = (1, 2, 3/2)$), coming from the coupling with magnetic subsystem. If we assume that these two quantum critical point do not affect each other, then we can write,

$$\chi_e^{-1} = \alpha + \beta T^2 - \gamma T^\nu \quad (15)$$

Where α, β, γ with $\beta, \gamma > 0$ are constant which varies from system to system and β and γ are proportional to u and w respectively. For $\nu = 1$ or $3/2$, the temperature dependence of static dielectric susceptibility will be dominated by anti-ferromagnetic quantum critical point with ($1/T^\nu$ increase) and there will be a maxima at a temperature $T_{max} = (\frac{2\beta}{\gamma\nu})^{\frac{1}{\nu-2}}$ as shown in figure[2]. For $\nu = 2$, there will

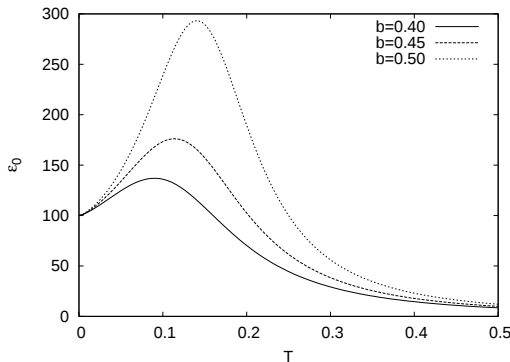


FIG. 2: Figure shows the temperature dependence of static dielectric susceptibility near both the anti-ferromagnetic and ferroelectric quantum critical point for various values of the parameter $b = \frac{\gamma}{\beta}$. Here $\nu = 3/2$, and $\alpha = 0.01$ and ϵ_0 and T are plotted in arbitrary scale.

be a competition between anti-ferromagnetic quantum critical point and ferroelectric quantum critical

point and depending on the values of α/β an anti-ferromagnetic quantum critical point dominated behavior with $1/T^2$ increase or a ferroelectric quantum critical point dominated behavior with $1/T^2$ decrease can be found in the static dielectric constant as shown in the figure[3].

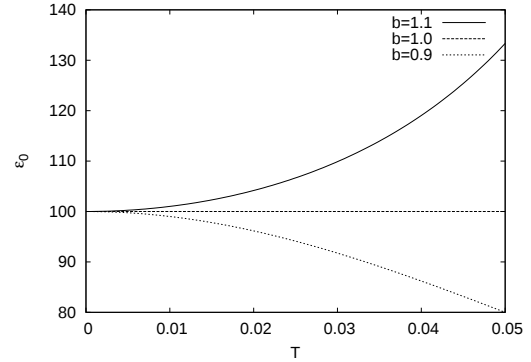


FIG. 3: Figure shows the temperature dependence of static dielectric susceptibility near both the anti-ferromagnetic and ferroelectric quantum critical point for various values of the parameter $b = \frac{\gamma}{\beta}$. Here $\alpha = 0.001$ and ϵ_0 and T are plotted in arbitrary scale.

DISCUSSION

In this work we presented a self consistent mean field theory to discuss the temperature and the magnetic field dependence of the static dielectric susceptibility of a magnetic quantum paraelectric at low temperature. In this material anti-ferromagnetic fluctuations are coupled to the polarization fluctuations and their interplay can lead to many interesting thermodynamic consequences when some non-thermal control parameters of both fluctuations are tuned to near critical values. We focus on the behavior of the system in presence of two such quantum critical points. Based on scaling argument near quantum critical points, we predict that there is a possibility that the low temperature suppression of the static dielectric susceptibility due to magnetic order can be compensated by polarization fluctuations. In that case the static dielectric susceptibility will take $1/T^2$ form as predicted for quantum critical ferroelectrics[1]. At present, up-to our knowledge, there is no report on experimental investigations on the simultaneous effects of two such quantum critical points. However we point out that, search for quantum critical points in this material, as was done in case of other quantum paraelectrics, can reveal more interesting phenomena as a result of

the interplay of two quantum critical points. This system, in many aspects is similar to the systems where anti-ferromagnetic order parameter is coupled to superconductivity[12].

Acknowledgment

The author would like to thank Prof. S. G. Mishra for many useful discussions.

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